BLF6G22S-45

Power LDMOS transistor

AMPLEON Product data sheet

Rev. 4 — 1 September 2015

1. Product profile

1.1 General description

45 W LDMOS power transistor for base station applications at frequencies from 2000 MHz to 2200 MHz.

Table 1. Typical performance

RF performance at $T_{case} = 25$ °C in a common source class-AB production test circuit.

Mode of operation	f	V _{DS}	P _{L(AV)}	Gp	η _D	ACPR
	(MHz)	(V)	(W)	(dB)	(%)	(dBc)
2-carrier W-CDMA	2110 to 2170	28	2.5	18.5	13	-48 <mark>[1]</mark>

^[1] Test signal: 3GPP; test model 1; 64 DPCH; PAR = 7.5 dB at 0.01 % probability on CCDF per carrier; carrier spacing 5 MHz.

CAUTION



This device is sensitive to ElectroStatic Discharge (ESD). Therefore care should be taken during transport and handling.

1.2 Features and benefits

- Typical 2-carrier W-CDMA performance at frequencies of 2110 MHz and 2170 MHz, a supply voltage of 28 V and an I_{Dq} of 405 mA:
 - ◆ Average output power = 2.5 W
 - ◆ Power gain = 18.5 dB (typ)
 - ◆ Efficiency = 13 %
 - ◆ ACPR = -48 dBc
- Easy power control
- Integrated ESD protection
- Excellent ruggedness
- High efficiency
- Excellent thermal stability
- Designed for broadband operation (2000 MHz to 2200 MHz)
- Internally matched for ease of use
- Compliant to Directive 2002/95/EC, regarding Restriction of Hazardous Substances (RoHS)

1.3 Applications

■ RF power amplifiers for W-CDMA base stations and multicarrier applications in the 2000 MHz to 2200 MHz frequency range

2. Pinning information

Table 2. Pinning

Pin	Description		Simplified outline	Graphic symbol
1	drain			
2	gate			1
3	source	[1]	3	2 — — 3 sym112

^[1] Connected to flange.

3. Ordering information

Table 3. Ordering information

Type number	Packag	Package				
	Name	Description	Version			
BLF6G22S-45	-	ceramic earless flanged package; 2 leads	SOT608B			

4. Limiting values

Table 4. Limiting values

In accordance with the Absolute Maximum Rating System (IEC 60134).

Symbol	Parameter	Conditions	Min	Max	Unit
V_{DS}	drain-source voltage		-	65	V
V_{GS}	gate-source voltage		-0.5	+13	V
T _{stg}	storage temperature		-65	+150	°C
Tj	junction temperature		-	225	°C

5. Thermal characteristics

Table 5. Thermal characteristics

Symbol	Parameter	Conditions	Тур	Unit
$R_{\text{th(j-case)}}$	thermal resistance from junction to case	T _{case} = 80 °C; P _L = 12.5 W (CW)	1.7	K/W

6. Characteristics

Table 6. Characteristics

 $T_i = 25$ °C per section; unless otherwise specified.

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
V _{(BR)DSS}	drain-source breakdown voltage	$V_{GS} = 0 \text{ V}; I_D = 0.5 \text{ mA}$	65	-	-	V
$V_{GS(th)}$	gate-source threshold voltage	V_{DS} = 10 V; I_{D} = 72 mA	1.4	1.9	2.4	V
V_{GSq}	gate-source quiescent voltage	V_{DS} = 28 V; I_{D} = 300 mA	1.65	2.15	2.65	V
I _{DSS}	drain leakage current	$V_{GS} = 0 \text{ V}; V_{DS} = 28 \text{ V}$	-	-	1.5	μΑ
I _{DSX}	drain cut-off current	$V_{GS} = V_{GS(th)} + 3.75 V;$ $V_{DS} = 10 V$	-	12.5	-	Α
I _{GSS}	gate leakage current	$V_{GS} = 11 \text{ V}; V_{DS} = 0 \text{ V}$	-	-	150	nA
9 _{fs}	forward transconductance	$V_{DS} = 10 \text{ V}; I_D = 3.5 \text{ A}$	-	5	-	S
R _{DS(on)}	drain-source on-state resistance	$V_{GS} = V_{GS(th)} + 3.75 \text{ V};$ $I_D = 2.5 \text{ A}$	-	0.2	-	Ω

7. Application information

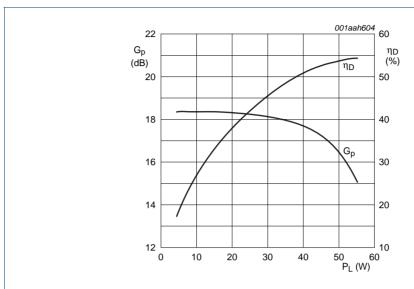
Table 7. Application information

Mode of operation: 2-carrier W-CDMA; PAR 7.5 dB at 0.01 % probability on CCDF; 3GPP test model 1; 1 to 64 PDPCH; f_1 = 2112.5 MHz; f_2 = 2117.5 MHz; f_3 = 2162.5 MHz; f_4 = 2167.5 MHz; RF performance at V_{DS} = 28 V; I_{Dq} = 405 mA; T_{case} = 25 °C; unless otherwise specified; in a class-AB production test circuit.

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
$P_{L(AV)}$	average output power		-	2.5	-	W
Gp	power gain	$P_{L(AV)} = 2.5 W$	17.3	18.5	19.7	dB
η _D	drain efficiency	$P_{L(AV)} = 2.5 W$	10.5	13	-	%
ACPR	adjacent channel power ratio	$P_{L(AV)} = 2.5 \text{ W}$	-	-48	-45	dBc

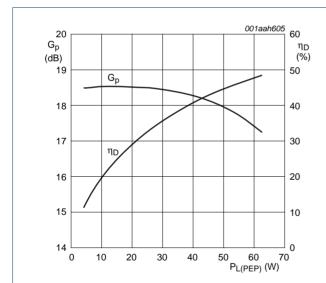
7.1 Ruggedness in class-AB operation

The BLF6G22S-45 is capable of withstanding a load mismatch corresponding to VSWR = 10 : 1 through all phases under the following conditions: V_{DS} = 28 V; I_{Dg} = 405 mA; P_L = 45 W (CW); f = 2170 MHz.



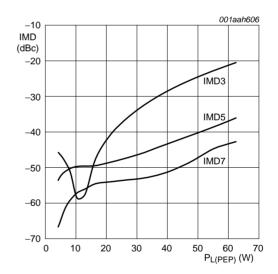
 V_{DS} = 28 V; I_{Dq} = 405 mA; f = 2170 MHz.

Fig 1. One-tone CW power gain and drain efficiency as functions of load power; typical values



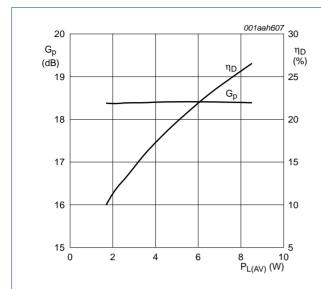
 V_{DS} = 28 V; I_{Dq} = 405 mA; f_1 = 2170 MHz; f_2 = 2170.1 MHz.

Fig 2. Two-tone CW power gain and drain efficiency as functions of peak envelope load power; typical values



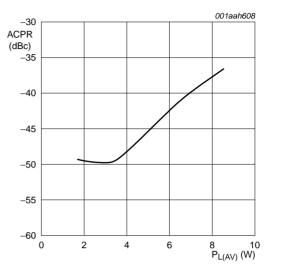
 V_{DS} = 28 V; I_{Dq} = 405 mA; f_1 = 2170 MHz; f_2 = 2170.1 MHz.

Fig 3. Intermodulation distortion as a function of peak envelope load power; typical values



 V_{DS} = 28 V; I_{Dq} = 405 mA; f_1 = 2162.5 MHz; f_2 = 2167.5 MHz; carrier spacing 5 MHz.

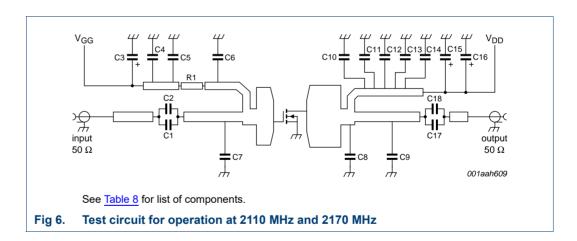
Fig 4. 2-carrier W-CDMA power gain and drain efficiency as functions of average load power; typical values

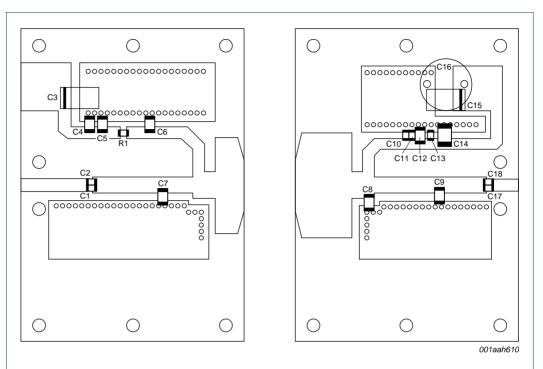


 V_{DS} = 28 V; I_{Dq} = 405 mA; f_1 = 2162.5 MHz; f_2 = 2167.5 MHz; carrier spacing 5 MHz.

Fig 5. 2-carrier W-CDMA adjacent power channel ratio as a function of average load power; typical values

8. Test information





Striplines are on a double copper-clad Rogers Duroid 5880 Printed-Circuit Board (PCB) with ϵ_r = 2.2 and thickness = 0.79 mm.

See Table 8 for list of components.

Fig 7. Component layout for 2110 MHz and 2170 MHz test circuit

Table 8. List of components

For test circuit, see Figure 6 and Figure 7.

Component	Description	Value	Remarks
C1, C2, C17, C18	multilayer ceramic chip capacitor	6.8 pF	<u>[1]</u>
C3, C15	tantalum capacitor	10 μF	
C4, C5	multilayer ceramic chip capacitor	1.5 μF	
C6, C12	multilayer ceramic chip capacitor	10 pF	[2]
C7	multilayer ceramic chip capacitor	0.5 pF	[2]
C8	multilayer ceramic chip capacitor	1.2 pF	[2]
C9	multilayer ceramic chip capacitor	1.0 pF	[2]
C10, C11	multilayer ceramic chip capacitor	100 nF	
C13	multilayer ceramic chip capacitor	220 nF	
C14	multilayer ceramic chip capacitor	4.7 μF	
C16	electrolytic capacitor	220 μF, 63 V	
R1	chip resistor	5.6 Ω	

^[1] American technical ceramics type 100A or capacitor of same quality.

^[2] American technical ceramics type 100B or capacitor of same quality.

9. Package outline

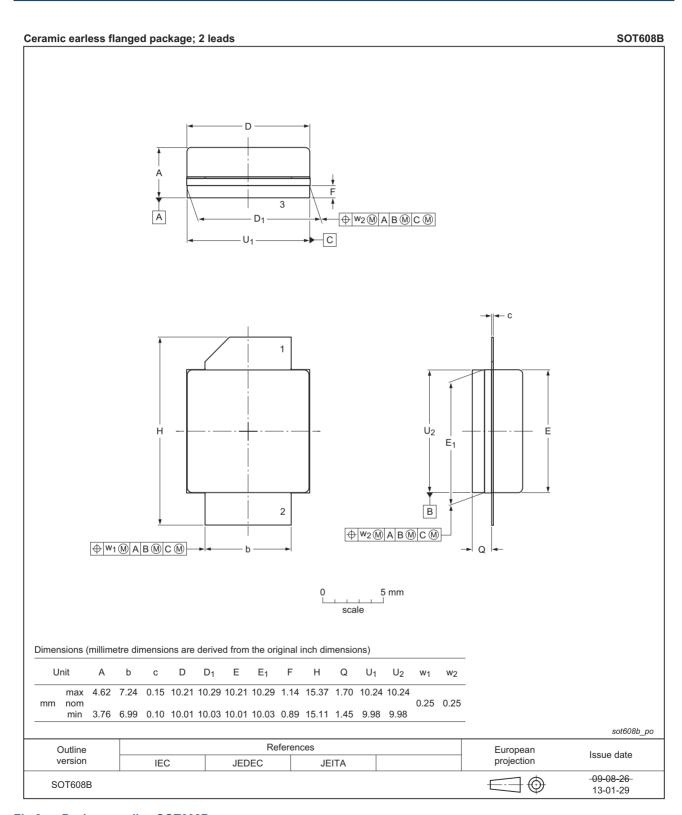


Fig 8. Package outline SOT608B

10. Abbreviations

Table 9. Abbreviations

Acronym	Description
3GPP	3rd Generation Partnership Project
CCDF	Complementary Cumulative Distribution Function
CW	Continuous Waveform
DPCH	Dedicated Physical CHannel
IMD	InterModulation Distortion
LDMOS	Laterally Diffused Metal-Oxide Semiconductor
PAR	Peak-to-Average power Ratio
PDPCH	transmission Power of the Dedicated Physical CHannel
RF	Radio Frequency
VSWR	Voltage Standing-Wave Ratio
W-CDMA	Wideband Code Division Multiple Access

11. Revision history

Table 10. Revision history

Document ID	Release date	Data sheet status	Change notice	Supersedes
BLF6G22S-45#4	20150901	Product data sheet	-	BLF6G22S-45_3
Modifications:	 The format of this document has been redesigned to comply with the new identity guidelines of Ampleon. Legal texts have been adapted to the new company name where appropriate. 			
BLF6G22S-45 v.3	20130311	Product data sheet	-	BLF6G22S-45_2
BLF6G22S-45_2	20080417	Product data sheet	-	BLF6G22-45_BLF6G22S-45_1
BLF6G22-45_BLF6G22S-45_1	20080219	Preliminary data sheet	-	-

12. Legal information

12.1 Data sheet status

Document status[1][2]	Product status[3]	Definition
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
Preliminary [short] data sheet	Qualification	This document contains data from the preliminary specification.
Product [short] data sheet	Production	This document contains the product specification.

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- [2] The term 'short data sheet' is explained in section "Definitions"
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14. Contents

1	Product profile
1.1	General description
1.2	Features and benefits
1.3	Applications
2	Pinning information
3	Ordering information
4	Limiting values
5	Thermal characteristics 2
6	Characteristics 3
7	Application information 3
7.1	Ruggedness in class-AB operation 3
8	Test information 5
9	Package outline
10	Abbreviations
11	Revision history
12	Legal information9
12.1	Data sheet status
12.2	Definitions9
12.3	Disclaimers
12.4	Trademarks10
13	Contact information
14	Contents

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